

PCN no.: PCN-092 rev.1.2.	.1	Date: 2016-06-07
Device affected:		Device version / Build Code:
nRF51822-QFAA		Goo, G10, G20, G30
nRF51822-CEAA nRF51822-QFAB		Doo, D1o, D2o, D3o Boo, B2o
52022 2.7.2		500, 520
Data sheet references:	Agreement reference:	Customers reference:
See Appendix 1	N/A	N/A
Impact: Does the change affect	-	
	No Yes – describe:	
2. Fit	No Yes – describe:	
3. Function	☐ No ☐ Yes – describe: See d	escription below
' ' '	No Pes – describe:	
Classification of change	Minor Major	
Loon of Donath otherwise office	ak a a saka ta a sa	
Impact: Does the change affec		
		weel MOO for a DE-10-2 CEAA variant
6. Fit 7. Function	NoYes – describe: NewNoYes – describe:	reel MOQ for nRF51822-CEAA variant
'	No ☐ Yes – describe:	
· · · · ·	Minor Major	
Description of change:		
New revision of the ICs, with th	ne following key improvements/changes:	
1. Radio and CPU conc	urrency	
CPU availability for applic		efits include reduced application latency and increased Devices include APIs to enable/disable this feature. Refer
2. Improved power effic	ciency	
300 uA reduction in active	e current for CPU executing code from flas	h.
Improved buck DC/DC re (application software onl	gulator. The new DC/DC only supplies the	Radio. Optimizations include automatic management improved power efficiency. Refer to the Product
3. Improved start-up tir	me for Power on Reset (POR) module	
Optimized POR module t	to provide faster start-up time across the w	whole supply range (1.8 to 3.6 V).
4. Fixes of anomalies	·	
	des a number of fixes of anomalies reporte	ed in nRF51822-PAN v2.4. For an updated list of
anomalies refer to the ne	w nRF51822-PAN v3.0.	
5. New container option	ns for the CSP package variants	
_	(Reel) MOQ changed from 3000 to 7000 nRF51822-CEAA-R7 with a MOQ of 1500	
Refer to the Product Spe	cification version 3.1 for more information.	
Specification version 3.1 and th	n electrical specifications for the new revisi ne nRF51 Reference Manual version 3.0. th reference to these documents.	ion are documented in the nRF51822 Product
Reason for change:		
_	nprovements of performance and power ef	fficiency.



Consequences of change:

1. Hardware

None. New revisions are drop-in compatible with the current revisions.

2. Teleregulatory and Bluetooth certification

Reference designs nRF₅1822-DF (QFN) and nRF₅1822-CEAA-DF (CSP) pass all telecommunications regulatory bodies' requirements with the stated product changes with no discernible performance change. A reassessment of design performance due to applicable telecommunications regulatory requirements is required for any product not identical to the referenced designs.

Bluetooth QDIDs are valid for the new device versions *). Bluetooth RF PHY conformance reassessment is recommended for all designs not identical to the referenced designs.

3. Software

None. New revisions are software compatible with the current revisions including software workarounds for fixed anomalies.

To verify this, Nordic has carried out compatibility testing with the following software revisions:

- S110 v5.2.1, v6.2.1, and v7.1
- S120 V1.0.1
- nRF51 SDK v6.1 and v7.0

Note that the SDK v7.0 is compatible *only* with the new nRF51-DK and not the nRF51822-DK or nRF51822-EK.

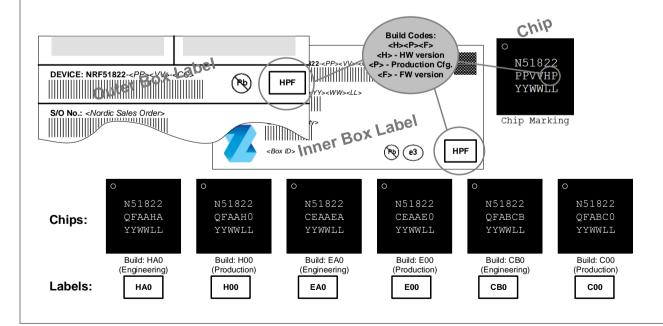
*) For more information on migrating to the new revisions refer to the white paper nWP-021 "Migrating from the 2nd to the 3rd revision of nRF51822", v.1.0.

Verification of change:

New revisions are approved and qualified under standard Nordic Semiconductor ASA QA procedures.

Marking/Shipping labels:

The new versions will be marked with new build codes as follows:





	ctive from:		
	nRF	51822-QFAA (6x6mm (QFN, 256kB Flash)
Build code	Wafer / assembly	Samples / reports	Active from
Hoo	TSMC Fab10 / AMKOR ATP	Now	2015-02-01
		Second source bu	ild codes:
H10	TSMC Fab10 / ASE ChungLi	Now	2015-09-01
H20	To be announced	To be announced	Samples + 90 days
H30	To be announced	To be announced	Samples + 90 days
	nRF5:	1822-CEAA (3.5x3.8mn	n CSP, 256kB Flash)
Build code	Wafer / assembly	Samples / reports	Active from
Eoo	TSMC Fab10 / Deca Technologies	Now	2015-02-01
	•	Second source bu	ild codes:
E10	TSMC Fab10 / ASE ChungLi	Now	2015-09-01
E20	To be announced	To be announced	Samples + 90 days
E30	To be announced	To be announced	Samples + 90 days
	nRF	51822-QFAB (6x6mm (QFN, 128kB Flash)
Build code	Wafer / assembly	Samples / reports	Active from
Coo	TSMC Fab10 / ASE ChungLi	Now	2015-02-01
		Second source bu	ild codes:
C10	TSMC Fab10 / Amkor ATP	October 2015	Samples + 60 days
C20	To be announced	To be announced	Samples + 90 days
C30	To be announced	To be announced	Samples + 90 days
or the se	visions. Depending on stock level o	f current revision the ac	dic will fulfill orders with the new revisions instead of the tual 'active from' date may be later. the exact schedule of production samples and qualification
lordic ma	ay on a limited basis support earlier	ramp-up on the new re	visions. Please contact Nordic sales for more information.
ast time	order:	Fi	nal shipment date:
015-12-3	21	20	016-06-30
attachme	ents: No	Xes – describe: A	Appendix 1
echnical	I contact at Nordic Semiconductor	·: C	Commercial contact at Nordic Semiconductor:
	diagonai agus \\C		l: " " " " " " " " " " " " " " " " " " "
/ww.nord	dicsemi.com, "Support"	V	<u>vww.nordicsemi.com</u> , "Contact Us"



Product Manager Sign: Date: 2016-06-07

Quality Director Date: 2016-06-07 Sign:

Please note that all last time buy orders are non-cancellable and non-returnable.

			Revision History
Revision	Date	Author	Comment
1.0	2014-10-28	T. Bonnerud	Initial Release
1.1	2015-04-31	T. Bonnerud	Updated build codes for nRF51822-QFAB
1.2	2015-07-03	D. Angco T. Bonnerud	Updated Active From dates for nRF51822-QFAA H10, nRF51822-CEAA E10 & nRF51822-QFAB C10. Added Last time order and final shipment date.
1.2.1	2016-06-07	D.Angco	Editorial update

Nordic Semiconductor ASA P.O. Box 2336 7004 Trondheim Norway

Tel.: +47 72 89 89 00



Appendix 1

Product change summary

This is a summary of the changes implemented in the relevant product documentation:

Module	nRF51 Series Reference Manual v3.0 chapter	nRF51822 PS v3.1 chapter	Part changed/added	Comment				
RAM	5.1.4	3.2.2	RAM organization	The RAM is divided into multiple RAM AHB slaves. Added description on how to organize usages of the RAM to take advantages of multiple RAM AHB slaves.				
Power	12.1.1	3.4.1	Power Supply	Changed how the DC/DC and Regulators are organized. The DC/DC converter is only controlling the radio voltage.				
	12.1.3	3.4.1.2	DC/DC Converter setup	Improved the DC/DC solution: Simplified how the DC/DC is controlled and operates. Removed the complexity around how it is controlled. Removed the startup time issue.				
	12.1.7	3.4.2.2	System ON mode	Improved description around Low Power and Constant Latency				
	12.1.12		Power-on reset	The Power-on reset module has been improved on the startup time for the whole VDD range (1.8 to 3.6 V). No change in the descriptive text but it's seen on the numbers specified for the Power-on reset module below. Both in chapter 7 Operation condition and section 8.2 Power Management.				
Timer		4.2	Timer/ Counter	Added description about 1 MHz mode.				
Radio	17.1.3		Maximum packet length	Correction of documentation error. No change in actual performance between current revision and new revisions. The combined length of SO, LENGTH, S1, and PAYLOAD is changed from "cannot exceed 255 bytes" to "cannot exceed 254 bytes".				
	29.6		UART	New section "Suspending the UART"				
	33		Software Interrupts	New chapter				
Operating Condition		7	Table 20	Parameter t _{R_VDD} is specified under new conditions to reflect the improved POR module. Old parameter description: Supply rise time (0V to 1.8 V) New parameter description: Supply rise time (0 V to VDD)				
				$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$				
System		8	Electrical specification	Changes in the electrical specification				
		8.1.2	Table 22	Symbol Old value New Units				
				I _{X16M.1M} New par. 250 μA				
		8.1.3	Table 23	Symbol Old value New Units value				
				IX32M.1M New par. 300 μA				
		8.1.4	Table 24	Symbol Old value New Units value				



Module	nRF51 Series Reference Manual v3.0 chapter	nRF51822 PS v3.1 chapter	Part changed/added	Comment				
				I _{RC16M.1M}		New par.	540	μA
				tstart,rc16M	(Typ.)	2,5	4,2	μs
				tstart,rc16M	(Max.)	3,5	5,2	μs
						tion error. No c rent revision ar		
		8.1.6	Table 26	Symbol		Old value	New value	Units
				t _{START,RC32k}	(Typ.)	100	390	μs
				tstart,rc32k	(Max.)	New par.	487	μs
				Correction of documentation error. No change in actual performance between current revision and new revisions.				
		8.1.7	Table 27	Symbol		Old value	New value	Units
				tstart,synt32	k	100	406	μs
						tion error. No c rent revision ar		
		8.2	Power management	The POR mode for the whole		oved so that it g (1.8 to 3.6 V).	ives a fast sta	ertup time
		8.2	Table 30	Symbol		Old value	New value	Units
				tpor, 1μs	(Min, Typ)	Removed.		
				t _{POR} , 50ms	(Min, Typ)	Removed.		
				tpor, 10μs	(Min.)	New par.	0,7	ms
				tpor, 10µs	(Typ.) (Max.)	New par. New par.	2.4 19	ms ms
				tPOR, 10µs tPOR, 1ms	(Min.)	New par.	1,7	ms
				tpor, 1ms	(Typ.)	New par.	3.4	ms
				tpor, 1ms	(Max.)	New par.	20	ms
				tpor, 10ms	(Min.)	New par.	11	ms
				tpor, 10ms	(Typ.)	New par.	12	ms
				tPOR, 10ms tPOR, 100ms	(Max.) (Min.)	New par. New par.	28 68	ms ms
				tPOR, 100ms	(Typ.)	New par.	101	ms
				tPOR, 100ms	(Max.)	New par.	115	ms
			Table 32	Symbol		Old value	New value	Units
				I ₁ V2XO16,1M		New par.	520	μA
				I1V2XO32,1M		New par. New par.	560 630	μΑ
				I ₁ V2RC16,1M txo	(Typ.)	New par. New par.	2,3	μA μs
				txo	(Max.)	New par.	5,3	μs
				IDCDC		Removed		
				tstart,dcdc		Removed		
		8.3	Table 33	Updated. Add	ed row " CP	ับ" and the colu	ımn " 1V7" .	
		8.4	Table 34	Symbol		Old value	New value	Units
				I _{CPU,FLASH}		4,4	4,1	mA
		8.5.3	Table 37 / Figure 11	enabled. • New ta		adio parameter cifying the Radio s enabled.		



Module	nRF51 Series Reference Manual v3.0 chapter	nRF51822 PS v3.1 chapter	Part changed/added	Comment			
				 Figure 11 gives the of VDD for selected 		tor (F _{DCDC}) as	function
		8.5.6	Table 40	Symbol	Old value	New value	Units
				trxchain (250 k)	12	12,5	μs
				trxchain (1 M)	2	3	μs
				trxchain (2 M)	2,5	2	μs
				Correction of documental performance between cur			
		8.7	Table 43	Symbol	Old value	New value	Units
				tстsн	New par.	1	μs
		8.8	Table 45	Symbol	Old value	New value	Units
				tcD	60	97	ns
				Correction of documentat performance between cur			
		8.13	Table 52	Symbol	Old value	New value	Units
				Itimer0/1/2,1M	New par.	4	μA
		8.15	Table 54	Improved the accuracy of Added a Note on T _{ACC} spe the range from 0°C to +60	cifying that the		oplicable in
		8.22		Corrected the timing specification for the NVMC mo			
		0.22		Corrected the timing spec	cification for the	NVMC mod	ıle.
		0.22	Table 61	Symbol	Old value	New	Units
		0.22		Symbol			_
		0.22			Old value	New	_
		6.22		Symbol teraseall (Typ.) teraseall (Max.) tpageerase (Typ.)	Old value Removed New par. Removed	New value	Units
		0.22		teraseall (Typ.) teraseall (Max.) tpageerase (Typ.) tpageeraseall (Max.)	Old value Removed New par. Removed New par.	New value	Units
		0.22		teraseall (Typ.) teraseall (Max.) tpageerase (Typ.) tpageeraseall (Max.) twrite (Typ.)	Old value Removed New par. Removed New par. Removed Removed	New value 22.3 22.3	Units
		0.22		teraseall (Typ.) teraseall (Max.) tpageerase (Typ.) tpageeraseall (Max.) twrite (Typ.) twrite,flash (Max.)	Old value Removed New par. Removed New par. Removed New par.	New value 22.3 22.3 46,3	Units ms ms μs
		0.22		teraseall (Typ.) teraseall (Max.) tpageerase (Typ.) tpageeraseall (Max.) twrite (Typ.) twrite,flash (Max.) twrite,flash (Max.)	Old value Removed New par. Removed New par. Removed New par. New par.	New value 22.3 22.3 46,3 39,3	ms ms us us us
		0.22		teraseall (Typ.) teraseall (Max.) tpageerase (Typ.) tpageeraseall (Max.) twrite (Typ.) twrite,flash (Max.) twrite,flash (Max.) twrite,ram,1st (Max.) twrite,ram,2nd (Max.)	Removed New par. Removed New par. Removed New par. Removed New par. New par.	New value 22.3 22.3 46,3 39,3 22,3	ms ms us
		0.22		teraseall (Typ.) teraseall (Max.) tpageerase (Typ.) tpageeraseall (Max.) twrite (Typ.) twrite,flash (Max.) twrite,flash (Max.)	Old value Removed New par. Removed New par. Removed New par. New par.	New value 22.3 22.3 46,3 39,3	ms ms us us us
		8.24		teraseall (Typ.) teraseall (Max.) tpageerase (Typ.) tpageeraseall (Max.) twrite (Typ.) twrite,flash (Max.) twrite,flash (Max.) twrite,ram,1st (Max.) twrite,ram,2nd (Max.)	Removed New par. Removed New par. Removed New par. Removed New par. New par.	New value 22.3 22.3 46,3 39,3 22,3	ms ms us us us us us us us us us